# Preliminary Technical Data 

## FEATURES

1 MHz PWM Frequency
Ultrasmall 8 -lead $3 \times 3$ Sq. mm Chip Scale Package
Automatic PWM to Power Saving Mode at Light Load
Fully Integrated 1.5 A Power Switch
3\% Output Regulation Accuracy over Temperature,
Line, and Load
100\% Duty Cycle Operation
Simple Compensation
Output Voltage: 1.25 V to 10 V
Small Inductor and MLC Capacitors
Low Quiescent Current while Pulse Skipping
Thermal Shutdown
Fully Integrated Soft Start
Cycle-by-cycle Current Limit
APPLICATONS
PDAs and Palmtop Computers
Notebook Computers
PCMCIA Cards
Bus Products
Portable Instruments
Industrial Systems

## GENERAL DESCRIPTION

The ADP3089 is a high frequency, non-synchronous PWM step-down DC-DC regulator with an integrated 1.5 A power switch in a space-saving chip scale package. It provides high efficiency, excellent dynamic response, and is very simple to use.
The ADP3089's 1 MHz switching frequency allows for small, inexpensive external components, and the current mode control loop is simple to compensate and eases noise filtering. It operates in PWM current mode under heavy loads and saves energy at lighter loads by switching automatically into Power Saving mode. Soft start is integrated completely on chip, as is the cycle-by-cycle current limit.

Capable of operating from 2.5 V to 11 V input with a typical output current of 1 A , it is ideal for portable, battery powered, industrial, PC and instrumentation applications. Supporting output voltages down to 1.25 V , the ADP3089 is ideal to generate low voltage rails, providing the optimal solution in its class for delivering power efficiently, responsively, and simply with minimal printed circuit board area.

The device is specified over the industrial temperature range of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, and is offered in an ultrasmall 8lead $3 \times 3$ square mm chip scale package.

## REV. PrE

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## FUNCTIONAL BLOCK DIAGRAM



Figure 1. Typical Application

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## ADP3089-SPECIFICATIONS ${ }^{1}\left(v_{I N}=+3.3 \mathrm{v}, \mathrm{t}_{\mathrm{A}}=-40^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SUPPLY <br> Input Voltage Range <br> Quiescent Current Operating <br> Shutdown <br> Ground Current Normal Operation <br> Thermal Shutdown Threshold | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}} \\ & \mathrm{I}_{\mathrm{Q}} \\ & \mathrm{I}_{\mathrm{SD}} \\ & \mathrm{I}_{\mathrm{GND}}{ }^{2} \\ & \mathrm{~T}_{\mathrm{SD}} \end{aligned}$ | DRV to GND $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=1 \mathrm{~A}, \\ & \mathrm{DRV}=\mathrm{GND} \end{aligned}$ <br> No load $\mathrm{V}_{\mathrm{COMP}}=0 \mathrm{~V}$ $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=1 \mathrm{~A}, \\ & \mathrm{DRV}=2 \mathrm{~V} \end{aligned}$ | 2.5 | 12 <br> 180 <br> 15 <br> 3 <br> 160 | 11 <br> 280 <br> 40 <br> 3.6 | V <br> mA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> mA <br> ${ }^{\circ} \mathrm{C}$ |
| OSCILLATOR <br> Oscillator Frequency <br> Minimum Sleep Duty Cycle <br> Maximum Duty Cycle <br> Wake up Hysteresis | $\mathrm{f}_{\mathrm{SW}}$ <br> $\mathrm{D}_{\text {PSM }}$ <br> $\mathrm{D}_{\text {MAX }}$ <br> $\mathrm{V}_{\text {HYST }}$ | FB voltage drops below $\mathrm{V}_{\text {REF }}$ | $\begin{aligned} & 0.75 \\ & 100 \\ & 20 \end{aligned}$ | $\begin{aligned} & 1 \\ & 14 \\ & 30 \end{aligned}$ | $\begin{aligned} & 1.25 \\ & 40 \end{aligned}$ | $\begin{aligned} & \mathrm{MHz} \\ & \% \\ & \% \\ & \mathrm{mV} \end{aligned}$ |
| OUTPUT SWITCH <br> Switch On Voltage <br> Current Limit Threshold <br> Leakage Current | $\begin{aligned} & \mathrm{V}_{\mathrm{IO}}^{3} \\ & \mathrm{I}_{\mathrm{LIM}} \end{aligned}$ | $\mathrm{I}_{\mathrm{L}}=1 \mathrm{~A}, \mathrm{FB}$ and DRV tied to GND $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}$ | 1.5 | $\begin{aligned} & .7 \\ & \\ & 1.7 \\ & 0.5 \end{aligned}$ | 1.0 2 | V <br> A <br> $\mu \mathrm{A}$ |
| ERROR AMPLIFIER <br> Reference Voltage Accuracy <br> Reference Voltage Line Regulation <br> Feedback Input Bias Current Maximum Output Current Short Circuit Current <br> Transconductance | $\mathrm{V}_{\mathrm{REF}}$ <br> $\mathrm{I}_{\mathrm{FB}}$ <br> $\mathrm{I}_{\text {COMP }}$, sc <br> $\mathrm{I}_{\text {COMP }}$, SD <br> $\mathrm{g}_{\mathrm{m}}$, EA | FB tied to COMP <br> FB tied to COMP, <br> $\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}$ to 12 V <br> soft start expired <br> $\mathrm{V}_{\text {COMP }}=0 \mathrm{~V}$, activating <br> shutdown <br> $\mathrm{V}_{\mathrm{FB}}$ to $\mathrm{I}_{\mathrm{COMP}}$ | $\begin{aligned} & 1.222 \\ & \\ & -50 \\ & 35 \end{aligned}$ | $\begin{aligned} & 1.245 \\ & .02 \\ & 1 \\ & 60 \\ & 20 \\ & 480 \end{aligned}$ | $\begin{gathered} 1.265 \\ \\ 50 \\ 85 \\ 40 \end{gathered}$ | V \%/V <br> nA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A} / \mathrm{V}$ |
| MODULATOR <br> Transconductance Control Offset Voltage Soft Start Time Shutdown Threshold Voltage Slope Compensation | $\mathrm{g}_{\mathrm{m}}$, MOD <br> $\mathrm{V}_{\text {PWM }}$, os $\mathrm{t}_{\mathrm{ss}}$ <br> $\mathrm{V}_{\text {COMP }}$, SD $\mathrm{m}_{\mathrm{SC}}$ | $\mathrm{V}_{\text {COMP }} \text { to } \mathrm{I}_{\mathrm{L}}$ <br> Effectively summed to $I_{\text {Sw }}$ | 340 | $\begin{aligned} & 1 \\ & 0.90 \\ & 250 \\ & 0.5 \end{aligned}$ | $\begin{aligned} & 600 \\ & 750 \end{aligned}$ | $\begin{aligned} & \mathrm{A} / \mathrm{V} \\ & \mathrm{~V} \\ & \mu \mathrm{~s} \\ & \mathrm{mV} \\ & \mathrm{~A} / \mu \mathrm{s} \end{aligned}$ |

## NOTES

1 All limits at temperature extremes are guaranteed via correlation using standard Statistical Quality Control (SQC).
2 For higher efficiency operation, tie the DRV pin to the output for $I_{L}<250 \mathrm{~mA}$, and $\mathrm{V}_{\text {IN }}>3 \mathrm{~V}$.
$3 \mathrm{~V}(\mathrm{IN})-\mathrm{V}(\mathrm{SW})$, includes voltage drop across internal current sensor.
Specifications subject to change without notice.

*This is a stress rating only; operation beyond these limits can cause the device to be permanently damaged. Unless otherwise specified, all voltages are referenced to GND.

ORDERING GUIDE

| Model | Temperature <br> Range | Package <br> Option | Branding <br> Information |
| :--- | :--- | :--- | :--- |
| ADP3089ACP | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $\mathrm{CSP}-83 \times 3$ | P 7 A |

## PIN FUNCTION DESCRIPTIONS

| Pin | Mnemonic | Function |
| :--- | :--- | :--- |
| 1,2 | IN | Power Supply Input. Both pins <br> must be connected. |
| 4,6 | GND | Ground. Both pins must be con- <br> nected. |
| 5 | FB | Feedback Loop Compensation <br> and Shutdown Input. An open <br> drain or collector used to pull <br> the pin to ground will shutdown <br> the device. |
| 7 | DRV | Feedback Voltage Sense Input. <br> This pin senses the voltage via <br> an external resistor divider. <br> This pin provides a separate <br> path for drive current to be con- <br> nected to ground. |
| 8 | SW | Switching Output. |

PIN CONFIGURATION


## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the device features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

OUTLINE DIMENSIONS
Dimensions shown in inches and (mm).
8 Lds Lead Frame Chip Scale Package (LFCSP)
$3 \times 3 \mathrm{~mm}$ Body
(CP-08)


CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

